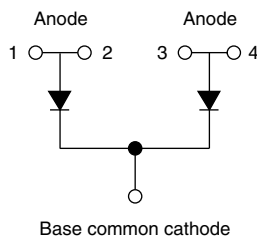


Not Insulated SOT-227 Power Module Ultrafast Rectifier, 200 A



SOT-227



FEATURES

- Not insulated package
- Ultrafast reverse recovery
- Ultrasoft reverse recovery current shape
- Optimized for power conversion: welding and industrial SMPS applications
- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- Direct mounting to heatsink
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



RoHS
COMPLIANT

DESCRIPTION

The UFB200CB40P not insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life time control, provide a ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, dc-to-dc converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

PRODUCT SUMMARY

| | |
|--|-------|
| V_R | 400 V |
| $I_{F(AV)}$ at $T_C = 146\text{ °C}$ per module ⁽¹⁾ | 200 A |
| t_{rr} | 89 ns |

Note

⁽¹⁾ All 4 anode terminals connected

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS |
|---|--------------------------|-----------------------|-------------|-------|
| Cathode to anode voltage | V_R | | 400 | V |
| Continuous forward current per diode | I_F ⁽¹⁾ | $T_C = 140\text{ °C}$ | 142 | A |
| Single pulse forward current per diode | I_{FSM} ⁽²⁾ | $T_C = 25\text{ °C}$ | 1300 | |
| Maximum power dissipation per module | P_D | $T_C = 140\text{ °C}$ | 368 | W |
| Operating junction and storage temperatures | T_J, T_{Stg} | | - 55 to 175 | °C |

Notes

⁽¹⁾ Both anode terminals connected;

Maximum I_{RMS} current per leg 200 A to do not exceed the maximum temperature of terminals, see fig. 6

⁽²⁾ 10 ms sine or 6 ms rectangular pulse

| ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified) | | | | | | |
|---|----------|---|------|------|------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | $I_R = 100\text{ }\mu\text{A}$ | 400 | - | - | V |
| Forward voltage | V_{FM} | $I_F = 100\text{ A}$ | - | 1.11 | 1.34 | |
| | | $I_F = 100\text{ A}, T_J = 125\text{ }^\circ\text{C}$ | - | 0.99 | 1.1 | |
| | | $I_F = 200\text{ A}$ | - | 1.3 | 1.6 | |
| | | $I_F = 200\text{ A}, T_J = 125\text{ }^\circ\text{C}$ | - | 1.22 | 1.4 | |
| Reverse leakage current | I_{RM} | $V_R = V_R\text{ rated}$ | - | - | 50 | μA |
| | | $T_J = 175\text{ }^\circ\text{C}, V_R = V_R\text{ rated}$ | - | - | 4 | mA |
| Junction capacitance | C_T | $V_R = 400\text{ V}$ | - | 100 | - | pF |

| DYNAMIC RECOVERY CHARACTERISTICS PER DIODE ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified) | | | | | | |
|--|-----------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | t_{rr} | $I_F = 1.0\text{ A}, di_F/dt = 400\text{ A}/\mu\text{s}, V_R = 30\text{ V}$ | - | 39 | - | ns |
| | | $T_J = 25\text{ }^\circ\text{C}$ | - | 89 | 136 | |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 184 | 235 | |
| Peak recovery current | I_{RRM} | $T_J = 25\text{ }^\circ\text{C}$ | - | 9 | 12 | A |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 20 | 25 | |
| Reverse recovery charge | Q_{rr} | $T_J = 25\text{ }^\circ\text{C}$ | - | 400 | 815 | nC |
| | | $T_J = 125\text{ }^\circ\text{C}$ | - | 1840 | 2940 | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|------------|-----------------------|------|------|-------|---------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Junction to case, single leg conducting | R_{thJC} | | - | - | 0.19 | $^\circ\text{C}/\text{W}$ |
| Junction to case, both leg conducting | | | - | - | 0.095 | |
| Case to heatsink, per module | R_{thCS} | Flat, greased surface | - | 0.05 | - | |
| Weight | | | - | 30 | - | g |
| Mounting torque | | | - | 1.3 | - | Nm |

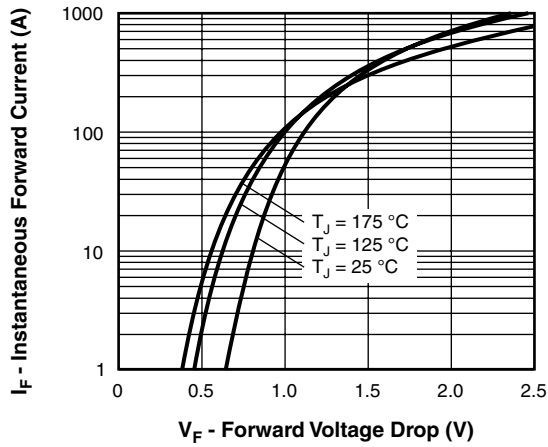


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Diode)

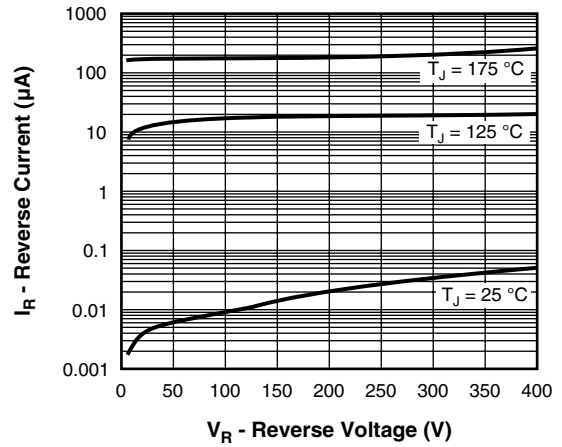


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

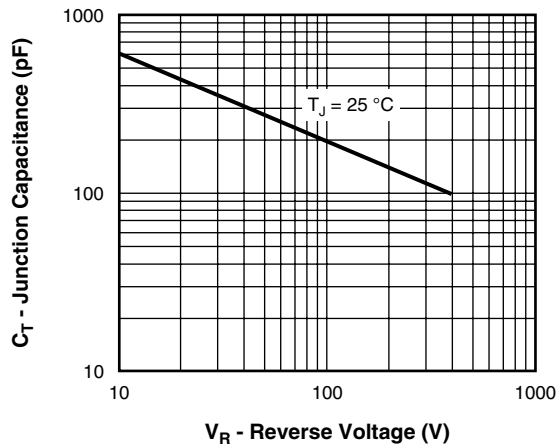


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

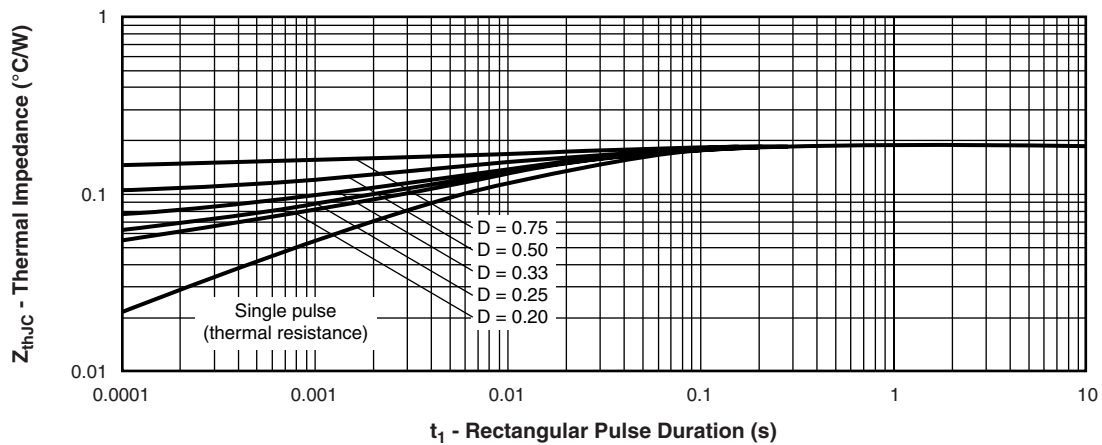


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

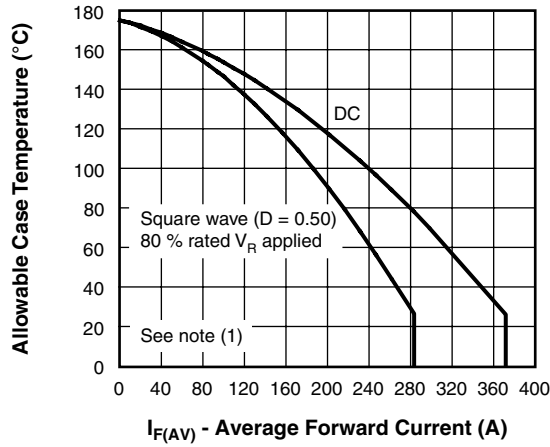


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

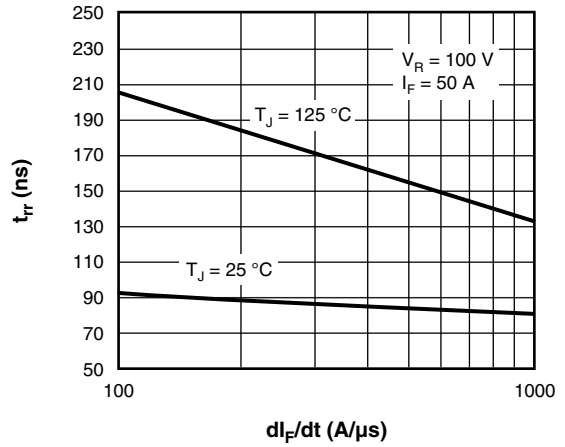


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

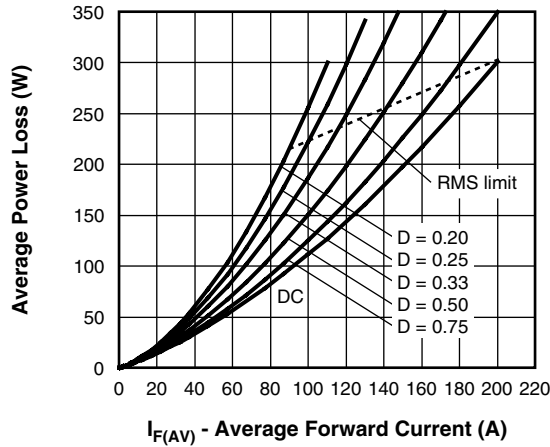


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

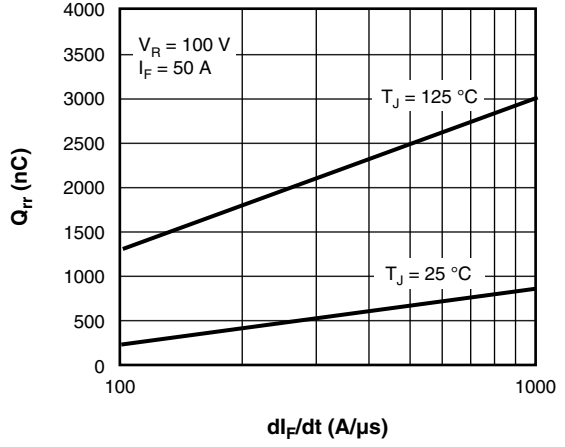


Fig. 8 - Typical Reverse Recovery Charge vs. di_F/dt

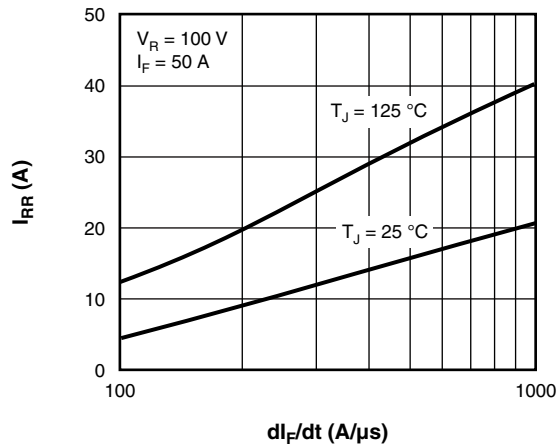


Fig. 9 - Typical Reverse Recovery Current vs. di_F/dt

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

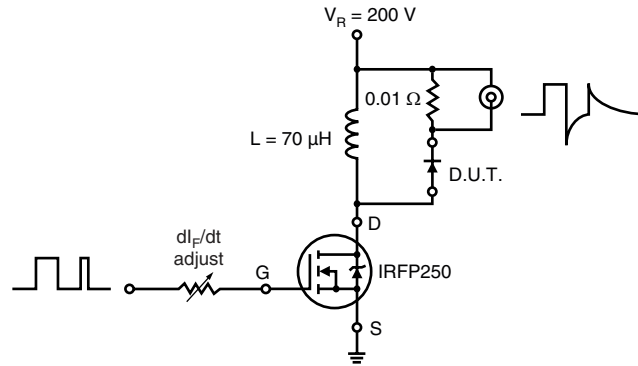
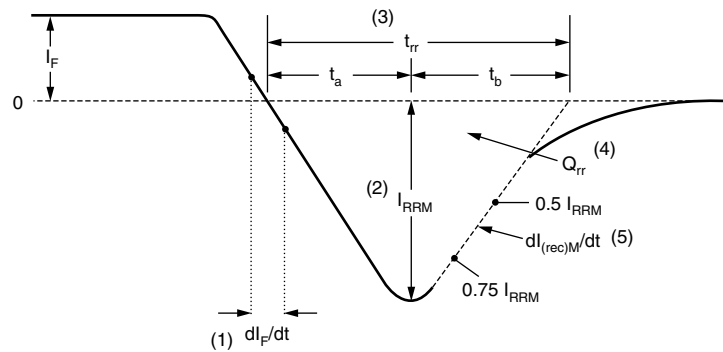


Fig. 10 - Reverse Recovery Parameter Test Circuit



(1) dl_p/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 11 - Reverse Recovery Waveform and Definitions

UFB200CB40P

Vishay High Power Products

Not Insulated SOT-227 Power Module
Ultrafast Rectifier, 200 A



ORDERING INFORMATION TABLE

| Device code | UF | B | 200 | C | B | 40 | P |
|-------------|----|---|-----|---|---|----|---|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |

- 1 - Ultrafast rectifier
- 2 - Ultrafast Pt diffused
- 3 - Current rating (200 = 200 A)
- 4 - Circuit configuration (2 common cathode diodes)
- 5 - Package indicator (SOT-227 standard not insulated)
- 6 - Voltage rating (40 = 400 V)
- 7 - • P = Lead (Pb)-free

Quantity per tube is 10 pcs, M4 screw and washer included

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--|
| Dimensions | www.vishay.com/doc?95036 |
| Packaging information | www.vishay.com/doc?95037 |



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